

Datasheet V2020.A.1

G4S12020PM

1200V/20A Silicon Carbide Power Schottky Barrier Diode

Features

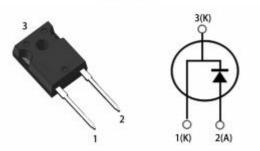
- Zero reverse recovery current
- Zero forward recovery voltage
- Temperature independent switching behavior
- High temperature operation
- High frequency operation

Key Characteristics V_{RRM} 1200 V I_F, T_c≤155°C 200 A Q_C 161 nC

Benefits

- •AEC-Q101 Qualified
- •Unipolar rectifier
- Substantially reduced switching losses
- No thermal run-away with parallel devices
- Reduced heat sink requirements
- •Support PPAP
- •Halorn-Free, RoHS compliant, REACH Qualified







Applications	

- SMPS, e.g., CCM PFC;
- Motor drives, Solar application, UPS, Wind turbine, Rail traction, EV/HEV

Part No.	Package Type	Marking
G4S12020PM	TO-247AC	G4S12020PM

Maximum Ratings

Parameter	Symbol	Test Condition	Value	Unit
Repetitive Peak Reverse Voltage	V _{RRM}		1200	V
Surge Peak Reverse Voltage	V _{RSM}		1200	V
DC Blocking Voltage	V _{DC}		1200	V
Continuous Forward Current	lF	T _c =25℃ T _c =125℃ T _c =155℃	64.5 35.2 20	А
Repetitive Peak Forward Surge Current	I _{FRM}	$T_{c}\mbox{=}25^{\circ}\mbox{C}$, tp=10ms , Half Sine Wave , D=0.3	100	А
Non-repetitive Peak Forward Surge Current	I _{FSM}	$$T_c=25^\circ\!\!\!\mathrm{C},\ tp=10ms$, Half Sine Wave	270	А
Power Dissipation	P _{TOT}	Tc=25℃ Tc=110℃	357 155	W W
Operating Junction	Tj		-55℃ to 175℃	°C
Storage Temperature	T _{stg}		-55℃ to 175℃	°C
Mounting Torque		M3 Screw 6-32 Screw	1 8.8	Nm lbf-in

Thermal Characteristics

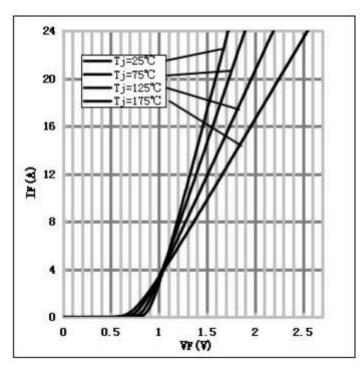
Parameter	Symbol	Test Condition	Value	Linit	
Farameter	Symbol	lest condition	Тур.	Unit	
Thermal resistance from junction to case	R_{thJC}		0.42	°C/W	

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Parameter	Symbol	Test Conditions	Тур.	Max.	Unit
		I _F =20A, Tj=25℃	1.42	1.6	V
Forward Voltage	VF	I _F =20A, Tj=175℃	2.14	2.4	V
Devenee Current		V _R =1200V, T _j =25℃	1.6	30	
Reverse Current	I _R	V _R =1200V, T _j =175℃	4.5	50	μΑ
		V _R =800V, T _j =150°C			
Total Capacitive Charge	Q _C	$Qc = \int_0^{VR} C(V)dV$	161	-	nC
	_	V _R =0V, T _j =25℃, f=1MHZ	2600	2700	
Total Capacitance	C	V _R =400V, T _j =25℃, f=1MHZ	140	145	pF
		V _R =800V, T _j =25℃, f=1MHZ	137	140	

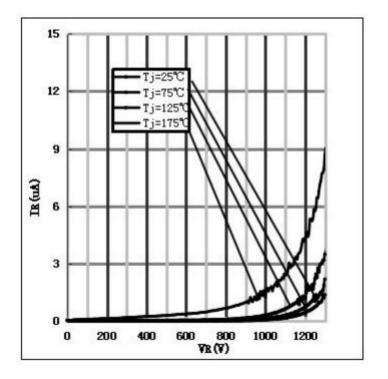
Electrical Characteristics

Performance Graphs

1) Forward IV characteristics as a function of Tj :

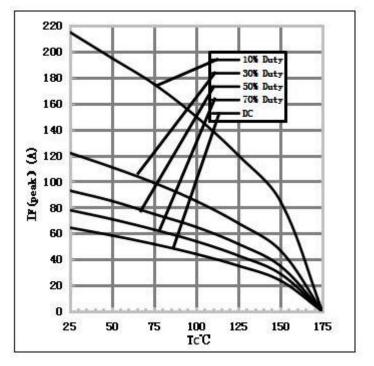


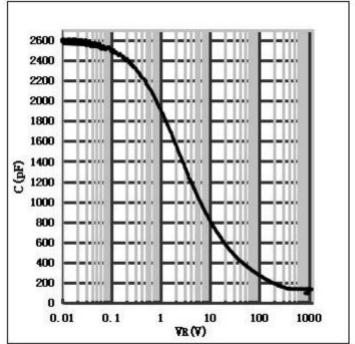
2) Reverse IV characteristics as a function of Tj :



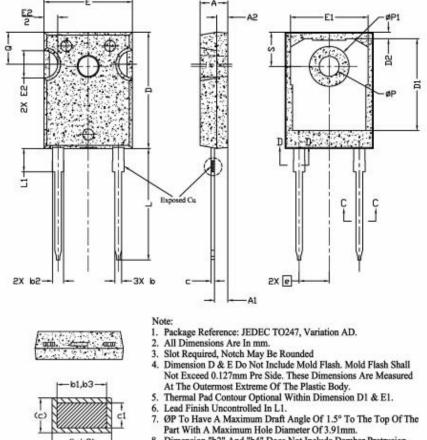
4) Capacitance vs. reverse voltage:

3) Current Derating:





Package TO-247AC



单位:mm

SYMBOL	DIMENSIONS			NOTES
SYMBOL	MIN.	NOM.	MAX	NOTES
A	4.83	5.02	5.21	1
A1	2.29	2.41	2.55	
A2	1.50	2.00	2.49	
ь	1.12	1.20	1.33	
b1	1.12	1.20	1.28	
b2	1.91	2.00	2.39	6
b3	1.91	2.00	2.34	
c	0.55	0.60	0.69	6
c1	0.55	0.60	0.65	
D	20.80	20.95	21.10	4
D1	16.25	16.55	17.65	5
D2	0.51	1.19	1.35	
E	15.75	15.94	16.13	4
E1	13.46	14.02	14.16	5
E2	4.32	4.91	5.49	3
۰		5.44BSC		
L	19.81	20.07	20.32	
L1	4.10	4.19	4.40	6
ØP	3.56	3.61	3.65	7
ØP1	8	7.19REF.	5	2
Q	5.39	5.79	6.20	
S	6.04	6.17	6.30	

(b,b2) 8. D

Section C--C,D--D

 Dimension "b2" And "b4" Does Not Include Dambar Protrusion. Allowable Dambar Protrusion Shall Be 0.10mm Total In Excess Of "b2" And "b4" Dimension At Maximum Material Condition. **Note**: The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC(RoHS2). RoHS Certification and other certifications can be obtained from GPT sales representatives or GPT website: http://globalpowertech.cn/English/index.asp

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